SiC Schottky Barrier Diode

Datasheet

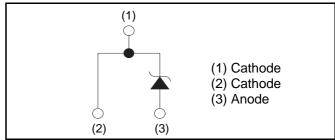
| V_{R} | 1200V |
|------------------|-------|
| I _F | 15A |
| $\overline{Q_C}$ | 51nC |

●Outline TO-220AC (1) (2) (3)

Features

- 1) Shorter recovery time
- 2) Reduced temperature dependence
- 3) High-speed switching possible

●Inner circuit



Applications

- PFC Boost Topology
- Secondary Side Rectification
- Data Center
- PV Power Conditioners

Packaging specifications

| er ackaging specifications | | |
|----------------------------|---------------------------|----------|
| | Packaging | Tube |
| | Reel size (mm) | - |
| Typo | Tape width (mm) | - |
| Type | Basic ordering unit (pcs) | 50 |
| | Packing code | С |
| | Marking | SCS215KG |

●Absolute maximum ratings (T_i = 25°C)

| Parameter | | Symbol | Value | Unit |
|---|---|--------------------|-------------------|------------------|
| Reverse voltage (re | petitive peak) | V_{RM} | 1200 | V |
| Reverse voltage (De | C) | V _R | 1200 | V |
| Continuous forward | current (T _c = 140°C) | I _F | 15 | А |
| Surge non- | PW=10ms sinusoidal, T _j =25°C | | 62 | А |
| repetitive forward | PW=10ms sinusoidal, T _j =150°C | I _{FSM} | 46 | А |
| current | PW=10μs square, T _j =25°C | | 240 | А |
| Repetitive peak forward current | | I _{FRM} | 68 ^{*1} | А |
| PW=10ms, T _j =25°C | | ۲.2 _ا ، | 19 | A ² s |
| i ² t value PW=10ms, T _j =150°C | | $\int i^2 dt$ | 11 | A ² s |
| Total power dissipation | | P_{D} | 180 ^{*2} | W |
| Junction temperature | | T _j | 175 | °C |
| Range of storage temperature | | T _{stg} | -55 to +175 | °C |

^{*1} T_c=100°C, T_i=150°C, Duty cycle=10% *2 T_c=25°C

●Electrical characteristics (T_j = 25°C)

| Parameter | Symbol Conditions - | Conditions | Values | | | Linit |
|-------------------------|---------------------|---|--------|------|------|-------|
| Parameter | | Min. | Тур. | Max. | Unit | |
| DC blocking voltage | V_{DC} | I _R =0.3mA | 1200 | - | - | V |
| | V _F | I _F =15A,T _j =25°C | - | 1.4 | 1.6 | V |
| Forward voltage | | I _F =15A,T _j =150°C | - | 1.8 | - | V |
| | | I _F =15A,T _j =175°C | - | 1.9 | - | V |
| Reverse current | I _R | V _R =1200V,T _j =25°C | - | 15 | 300 | μΑ |
| | | V _R =1200V,T _j =150°C | - | 120 | - | μΑ |
| | | V _R =1200V,T _j =175°C | - | 195 | - | μΑ |
| Total capacitance | С | V _R =1V,f=1MHz | - | 790 | - | pF |
| | | V _R =800V,f=1MHz | - | 64 | - | pF |
| Total capacitive charge | Q _C | V _R =800V,di/dt=500A/μs | - | 51 | - | nC |
| Switching time | t _C | V _R =800V,di/dt=500A/μs | - | 18 | - | ns |

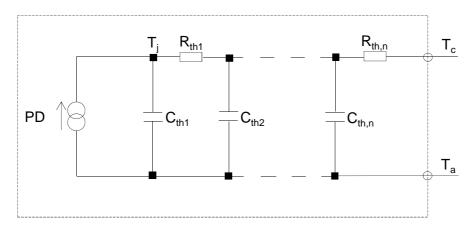
●Thermal characteristics

| Parameter | Symbol | Conditions | Values | | | Unit |
|--------------------|----------------------|------------|--------|------|------|-------|
| | | | Min. | Тур. | Max. | Offic |
| Thermal resistance | $R_{\text{th(j-c)}}$ | - | - | 0.67 | 0.80 | °C/W |

● Typical Transient Thermal Characteristics

| Symbol | Value | Unit |
|------------------|----------|------|
| R _{th1} | 1.24E-01 | |
| R _{th2} | 3.92E-01 | K/W |
| R _{th3} | 1.54E-01 | |

| Symbol | Value | Unit |
|-----------|----------|------|
| C_{th1} | 3.81E-03 | |
| C_{th2} | 4.44E-03 | Ws/K |
| C_{th3} | 6.02E-02 | |



•Electrical characteristic curves

Fig.1 V_F - I_F Characteristics

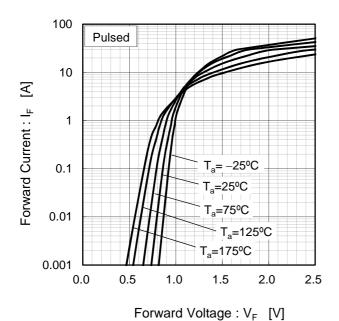
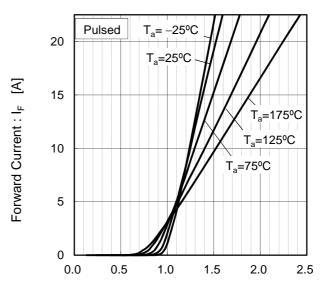


Fig.2 V_F - I_F Characteristics



Forward Voltage : V_F [V]

Fig.3 V_R - I_R Characteristics

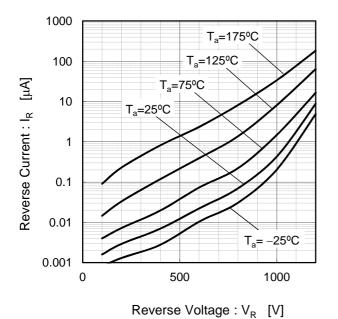
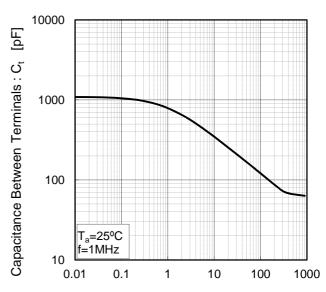


Fig.4 V_R - C_t Characteristics



Reverse Voltage : V_R [V]

Electrical characteristic curves

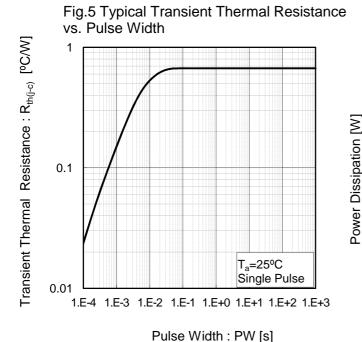
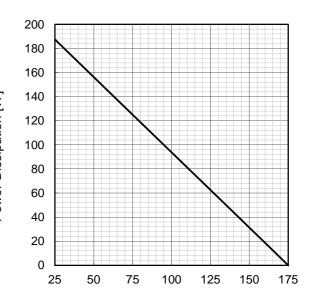
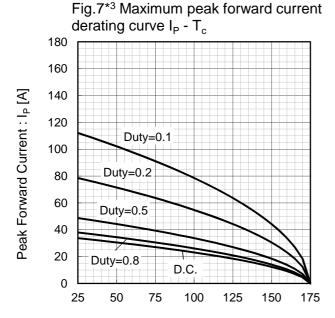


Fig.6 Power Dissipation



Case Temperature : T_c [°C]



Peak Forward Current : I_P [A]

derating curve I_P - T_c (Not guaranteed) 180 160 Duty=0.1 140 120 Duty=0.2 100 80 Duty=0.5 60 40 Duty=0.8 20 D.C. 0 25 50 75 100 125 150 175

Fig.8*4 Typical peak forward current

Case Temperature : T_c [°C] *3 Based on max Vf, max $R_{th(j-c)}$ Valid for switching of above 10kHz, excluding D.C. curve.

Case Temperature : T_c [°C]
*4 Based on typ Vf, typ R_{th(j-c)}
Typical value, not guaranteed
Valid for switching of above 10kHz,
excluding D.C. curve

•Electrical characteristic curves

Fig.9 Surge non-repetitive forward current vs. Pulse width (Sinusoidal waveform)

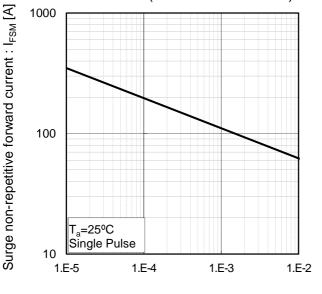
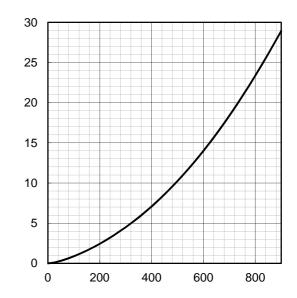


Fig.10 Typical capacitance store energy



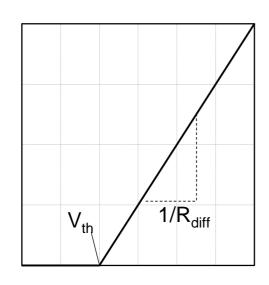
Capacitance stored energy ։ $\mathsf{E}_{\mathrm{C}}[\mu J]$

Reverse Voltage: V_R [V]

Symplified forward characteristic model

Fig.11 Equivalent forward current curve

Pulse Width: PW [s]



Forward Voltage : $V_{\rm F}$

$$V_F = V_{th} + R_{diff} I_F$$

$$\begin{aligned} &V_{th}\left(\ T_{j}\ \right) = a_{0} + a_{1}\,T_{j} \\ &R_{diff}\left(\ T_{j}\ \right) = b_{0} + b_{1}\,T_{j} + b_{2}\,T_{j}^{2} \end{aligned}$$

| Symbol | Typical Value | Unit |
|----------------|---------------|-------------------|
| a ₀ | 9.93E-01 | V |
| a ₁ | -1.27E-03 | V/°C |
| b_0 | 2.43E-02 | Ω |
| b ₁ | 1.37E-04 | Ω/°C |
| b ₂ | 8.87E-07 | Ω/°C ² |

 T_i in °C; -55 °C < T_i < °C; I_F < 30 A

Forward Current: IF

Notes

- 1) The information contained herein is subject to change without notice.
- Before you use our Products, please contact our sales representative and verify the latest specifications:
- 3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors.

 Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Poducts beyond the rating specified by ROHM.
- 4) Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.
- 5) The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.
- 6) The Products specified in this document are not designed to be radiation tolerant.
- 7) For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative: transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, and power transmission systems.
- 8) Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.
- 9) ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.
- 10) ROHM has used reasonable care to ensur the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.
- 11) Please use the Products in accordance with any applicable environmental laws and regulations, such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.
- 12) When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.
- This document, in part or in whole, may not be reprinted or reproduced without prior consent of ROHM.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Schottky Diodes & Rectifiers category:

Click to view products by ROHM manufacturer:

Other Similar products are found below:

MA4E2039 D1FH3-5063 MBR0530L-TP MBR10100CT-BP MBR1545CT MMBD301M3T5G RB160M-50TR RB551V-30

BAS16E6433HTMA1 BAT 54-02LRH E6327 NSR05F40QNXT5G NTE555 JANS1N6640 SB07-03C-TB-H SB1003M3-TL-W SK310-T

SK32A-LTP SK33A-TP SK34B-TP SS3003CH-TL-E GA01SHT18 CRS10I30A(TE85L,QM MA4E2501L-1290 MBRB30H30CT-1G

SB007-03C-TB-E SK32A-TP SK33B-TP SK35A-TP SK38B-TP NRVBM120LT1G NTE505 NTSB30U100CT-1G SS15E-TP VS-6CWQ10FNHM3 ACDBA1100LR-HF ACDBA1200-HF ACDBA140-HF ACDBA2100-HF ACDBA3100-HF CDBQC0530L-HF

CDBQC0240LR-HF ACDBA340-HF ACDBA260LR-HF ACDBA1100-HF SK310B-TP MA4E2502L-1246 MA4E2502H-1246

NRVBM120ET1G NSR01L30MXT5G NTE573